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Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control

Rev. 1 — 12 July 2012

Product data sheet

1. General description

The 74HC4852-Q100; 74HCT4852-Q100 are high-speed Si-gate CMOS devices and are specified in compliance with JEDEC standard no. 7A.

The 74HC4852-Q100; 74HCT4852-Q100 are dual 4-channel analog multiplexers/demultiplexers with common select inputs (S0 and S1). Both multiplexers have a common active LOW enable input (\overline{E}), four independent inputs/outputs (nY0 to nY3) and two common inputs/outputs (1Z, 2Z). The devices feature injection-current effect control, which has excellent value in automotive applications where voltages in excess of the supply voltage are common.

With \overline{E} LOW, two of the eight switches are selected (low impedance ON-state) by S0 and S1. With \overline{E} HIGH, all switches are in the high-impedance OFF-state, independent of S0 and S1.

The injection-current effect control allows signals at disabled analog input channels to exceed the supply voltage without affecting the signal of the enabled analog channel. This eliminates the need for external diode/resistor networks typically used to keep the analog channel signals within the supply-voltage range.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Injection-current cross coupling < 1 mV/mA</p>
- Wide supply voltage range from 2.0 V to 6.0 V for 74HC4852-Q100
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pf, R = 0 Ω)
- Latch-up performance exceeds 100 mA per JESD 78 Class II level A
- Low ON-state resistance:
 - 400 Ω (typical) at V_{CC} = 2.0 V
 - 215 Ω (typical) at V_{CC} = 3.0 V
 - 120 Ω (typical) at V_{CC} = 3.3 V
 - 76 Ω (typical) at V_{CC} = 4.5 V
 - 59 Ω (typical) at V_{CC} = 6.0 V



Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control

3. Applications

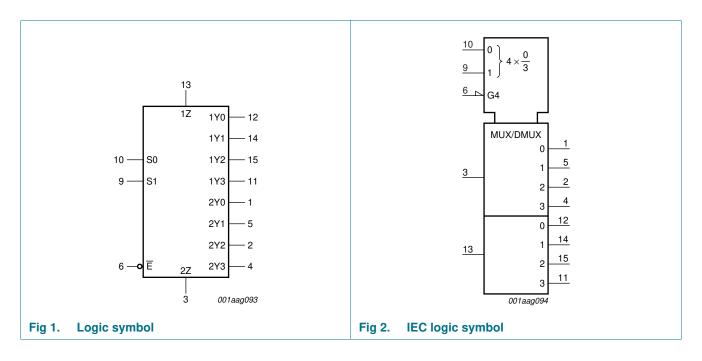
- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating
- Automotive application

4. Ordering information

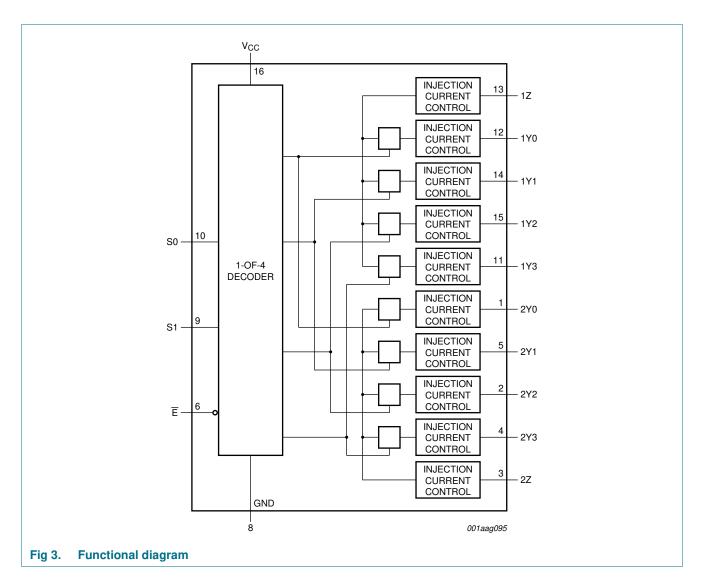
Table 1.Ordering information

Type number	Package									
	Temperature range	Name	Description	Version						
74HC4852D-Q100	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1						
74HCT4852D-Q100		body width 3.9 mm								
74HC4852PW-Q100	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1						
74HCT4852PW-Q100			body width 4.4 mm							
74HC4852BQ-Q100	–40 °C to +125 °C	DHVQFN16		SOT763-1						
74HCT4852BQ-Q100			very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm							

5. Functional diagram



Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control

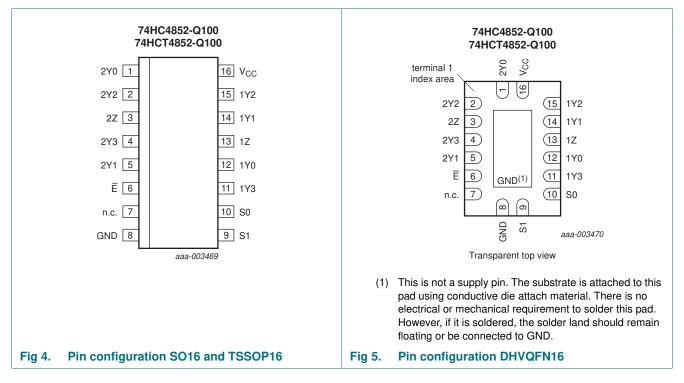


74HC_HCT4852_Q100

Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control

6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
2Y0	1	independent input/output
2Y2	2	independent input/output
2Z	3	common input/output
2Y3	4	independent input/output
2Y1	5	independent input/output
Ē	6	enable input (active LOW)
n.c.	7	not connected
GND	8	ground (0 V)
S1	9	select input
S0	10	select input
1Y3	11	independent input/output
1Y0	12	independent input/output
1Z	13	common input/output
1Y1	14	independent input/output
1Y2	15	independent input/output
V _{CC}	16	supply voltage

74HC HCT4852 Q100

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Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control

7. Functional description

Table 3. Fund	ction table ^[1]		
Input			Channel ON
E	S1	SO	
L	L	L	nY0 to nZ
L	L	Н	nY1 to nZ
L	Н	L	nY2 to nZ
L	Н	Н	nY3 to nZ
Н	Х	Х	-

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care.

8. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

					,
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
VI	input voltage		<u>[1]</u> –0.5	$V_{CC} + 0.5$	V
V _{SW}	switch voltage		2 –0.5	$V_{CC} + 0.5$	V
I _{IK}	input clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I} > V_{\rm CC}$ + 0.5 V	-	±20	mA
I _{SK}	switch clamping current	V_{SW} < –0.5 V or V_{SW} > V_{CC} + 0.5 V	-	±20	mA
I _{SW}	switch current	V_{SW} > –0.5 V or V_{SW} < V_{CC} + 0.5 V	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	<u>[3]</u> _	500	mW

[1] The minimum and maximum input voltage rating may be exceeded if the input clamping current rating is observed.

[2] The minimum and maximum switch voltage rating may be exceeded if the switch clamping current rating is observed.

[3] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.
 For TSSOP16 package: P_{tot} derates linearly with 5.5 mW/K above 60 °C.
 For DHVQFN16 packages: P_{tot} derates linearly with 4.5 mW/K above 60 °C.

Table F

74HC4852-Q100; 74HCT4852-Q100

Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control

9. Recommended operating conditions

Decomposed of execting conditions

Symbol	Parameter	Conditions	74H	74HC4852-Q100			ICT4852-	Q100	Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	-	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V_{CC}	0	-	V_{CC}	V
V _{SW}	switch voltage		0	-	V_{CC}	0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	-	+125	-40	-	+125	°C
$\Delta t / \Delta V$	input transition rise and	$V_{CC} = 2.0 V$	-	6.0	1 0 0 0	-	-	-	ns/V
	fall rate	$V_{CC} = 3.0 V$	-	6.0	800	-	-	-	ns/V
		$V_{CC} = 3.3 V$	-	6.0	800	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	6.0	500	-	6.0	500	ns/V
		$V_{CC} = 6.0 V$	-	6.0	400	-	-	-	ns/V

10. Static characteristics

Table 6. R_{ON resistance}

At recommended operating conditions; voltages are referenced to GND (ground 0 V); For test circuit see Figure 8.

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC485	2-Q100									
R _{ON(peak)}		$V_I = V_{CC}$ to GND; $\overline{E} = V_{IL}$								
	(peak)	$V_{CC} = 2.0 \text{ V}; \text{ I}_{SW} = 2 \text{ mA}$	-	400	650	-	670	-	700	Ω
		V_{CC} = 3.0 V; $I_{SW} \leq 2 \mbox{ mA}$	-	215	330	-	360	-	380	Ω
		V_{CC} = 3.3 V; $I_{SW} \leq 2 \mbox{ mA}$	-	120	270	-	305	-	345	Ω
		V_{CC} = 4.5 V; $I_{SW} \leq 2 \mbox{ mA}$	-	76	210	-	240	-	270	Ω
		V_{CC} = 6.0 V; $I_{SW} \leq 2 \mbox{ mA}$	-	59	195	-	220	-	250	Ω
ΔR_{ON}	ON resistance	$V_{I}=0.5\times V_{CC};\overline{E}=V_{IL}$								
	mismatch between channels	$V_{CC} = 2.0 \text{ V}; \text{ I}_{SW} = 2 \text{ mA}$	-	4	10	-	15	-	20	Ω
		V_{CC} = 3.0 V; $I_{SW} \leq 2 \mbox{ mA}$	-	2	8	-	12	-	16	Ω
		V_{CC} = 3.3 V; $I_{SW} \leq 2 \mbox{ mA}$	-	2	8	-	12	-	16	Ω
		V_{CC} = 4.5 V; $I_{SW} \leq$ 2 mA	-	2	8	-	12	-	16	Ω
		V_{CC} = 6.0 V; $I_{SW} \leq 2 \mbox{ mA}$	-	3	9	-	13	-	18	Ω
74HCT48	52-Q100									
R _{ON(peak)}	ON resistance	$V_{I} = V_{CC}$ to GND; $\overline{E} = V_{IL}$								
	(peak)	V_{CC} = 4.5 V; $I_{SW} \leq 2 \mbox{ mA}$	-	76	210	-	240	-	270	Ω
ΔR_{ON}	ON resistance	$V_I = 0.5 \times V_{CC}; \overline{E} = V_{IL}$								
	mismatch between channels	V_{CC} = 4.5 V; $I_{SW} \le 2 \text{ mA}$	-	2	8	-	12	-	16	Ω

74HC_HCT4852_Q100

Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control

Table 7. Injection current coupling

At recommended operating conditions; voltages are referenced to GND (ground 0 V); For test circuit see Figure 9.

Symbol	Parameter	Conditions	74H	IC4852/G	2100	74H	CT4852/0	Q100	Unit
			Min	Typ[1]	Max	Min	Typ[1]	Max	
$T_{amb} = -4$	0 °C to +125 °C								
ΔV_O	output voltage	$ I_{SW} \le 1 \text{ mA}; \text{ R}_S \le 3.9 \text{ k}\Omega$ [2][3	3]						
	variation	$V_{CC} = 3.3 V$	-	0.05	1	-	-	-	mV
		$V_{CC} = 5.0 V$	-	0.03	1	-	0.03	1	mV
		$ I_{SW} \leq 10 \text{ mA}; R_S \leq 3.9 \text{ k}\Omega$							
		$V_{CC} = 3.3 V$	-	0.55	5	-	-	-	mV
		$V_{CC} = 5.0 V$	-	0.27	5	-	0.27	5	mV
		$ I_{SW} \leq 1 \text{ mA}; \text{ R}_S \leq 20 \text{ k}\Omega$							
		$V_{CC} = 3.3 V$	-	0.04	2	-	-	-	mV
		$V_{CC} = 5.0 V$	-	0.03	2	-	0.03	2	mV
		$ I_{SW} \leq 10 \text{ mA}; R_S \leq 20 \text{ k}\Omega$							
		$V_{CC} = 3.3 V$	-	0.56	20	-	-	-	mV
		$V_{CC} = 5.0 V$	-	0.48	20	-	0.48	20	mV

[1] Typical values are measured at $T_{amb} = 25 \text{ °C}$.

[2] ΔV_O here is the maximum variation of output voltage of an enabled analog channel when current is injected into any disabled channel.

[3] I_{SW} = total current injected into all disabled channels.

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

				25 °C		–40 °C t	o +85 °C	–40 °C to +125 °C		
Symbol	Parameter	Conditions	Min	Тур	Max	Min	Max	Min	Max	Unit
74HC48	52-Q100		'				1			
V _{IH}	HIGH-level	control inputs								
	input voltage	$V_{CC} = 2.0 V$	1.5	-	-	1.5	-	1.5	-	V
	vollage	$V_{CC} = 3.0 V$	2.1	-	-	2.1	-	2.1	-	V
		$V_{CC} = 3.3 V$	2.3	-	-	2.3	-	2.3	-	V
		$V_{CC} = 4.5 V$	3.15	-	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	-	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	control inputs								
	input voltago	$V_{CC} = 2.0 V$	-	-	0.5	-	0.5	-	0.5	V
	voltage	$V_{CC} = 3.0 V$	-	-	0.9	-	0.9	-	0.9	V
		$V_{CC} = 3.3 V$	-	-	1.0	-	1.0	-	1.0	V
		$V_{CC} = 4.5 V$	-	-	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	-	1.8	-	1.8	-	1.8	V
I _I	input leakage	control inputs; $V_I = GND$ or V_{CC}								
	current	$V_{CC} = 6.0 V$	-	-	±0.1	-	±0.1	-	±1.0	μA

Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control

Table 8. Static characteristics ... continued

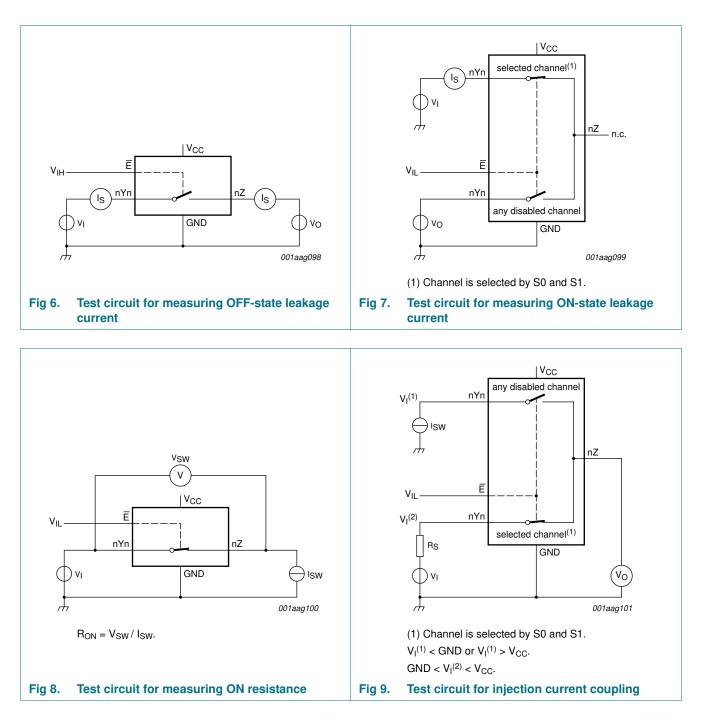
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

				25 °C		–40 °C t	o +85 °C	-40 °C te	o +125 °C	;
Symbol	Parameter	Conditions	Min	Тур	Max	Min	Max	Min	Max	Un
S(OFF)	OFF-state leakage current	$ \overline{E} = V_{IH}; V_I = GND \text{ or } V_{CC}; V_O = V_{CC} \text{ or } GND; V_{CC} = 6.0 V; see Figure 6 $		I				I		
		nYn; per channel	-	-	±0.1	-	±0.5	-	±1.0	μA
		nZ; all channels	-	-	±0.2	-	±2.0	-	±4.0	μA
I _{S(ON)}	ON-state leakage current	$ \overline{E} = V_{IL}; V_I = GND \text{ or } V_{CC}; V_O = V_{CC} \text{ or } GND; V_{CC} = 6.0 V; see Figure 7 $	-	-	±0.1	-	±0.5	-	±1.0	μA
lcc	supply	$V_I = GND \text{ or } V_{CC}$								
	current	$V_{CC} = 6.0 V$	-	-	2.0	-	5.0	-	20.0	μA
Cı	input capacitance	S0, S1, S2 and \overline{E}	-	2	10	-	10	-	10	pF
C _{sw}	switch	nZ; OFF-state	-	15	40	-	40	-	40	pF
	capacitance	nYn; OFF-state	-	3	15	-	15	-	15	pF
74HCT48	352-Q100									
VIH	HIGH-level	control inputs								
	input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
VIL	LOW-level	control inputs								
	input voltage	V_{CC} = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
I	input leakage	control inputs; $V_I = GND$ or V_{CC}								
	current	V _{CC} = 5.5 V	-	-	±0.1	-	±0.1	-	±1.0	μA
I _{S(OFF)}	OFF-state leakage current	$ \overline{E} = V_{IH}; V_I = GND \text{ or } V_{CC}; V_O = V_{CC} \text{ or } GND; V_{CC} = 5.5 V; see Figure 6 $								
		per channel	-	-	±0.1	-	±0.5	-	±1.0	μA
		all channels	-	-	±0.2	-	±2.0	-	±4.0	μA
I _{S(ON)}	ON-state leakage current	$\label{eq:eq:constraint} \begin{split} \overline{E} &= V_{IL}; \ V_I = GND \ or \ V_{CC}; \\ V_O &= V_{CC} \ or \ GND; \\ V_{CC} &= 5.5 \ V; \ see \ \underline{Figure \ 7} \end{split}$	-	-	±0.1	-	±0.5	-	±1.0	μA
I _{CC}	supply	$V_I = GND \text{ or } V_{CC}$								
	current	$V_{CC} = 5.5 V$	-	-	2.0	-	5.0	-	20.0	μA
∆l _{CC}	additional supply current	control inputs; $V_I = V_{CC} - 2.1 V$; other inputs at V _{CC} or GND; $V_{CC} = 4.5 V$ to 5.5 V; $I_O = 0 A$	-	-	300	-	370	-	370	μA
Cı	input capacitance	S0, S1, S2 and \overline{E}	-	2	10	-	10	-	10	pF
C _{sw}	switch capacitance	nZ; OFF-state	-	9	40	-	40	-	40	pF
		nYn; OFF-state	-	3	15	-	15	-	15	pF

74HC_HCT4852_Q100

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Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control



Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control

11. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V); for load circuit see Figure 14.

Symbol	Parameter	Conditions			25 °C		–40 °C	to +85 °C	-40 °C	to +125 °C	Uni
				Min	Тур	Max	Min	Max	Min	Max	
74HC48	52-Q100										
pd	propagation delay	nZ, nYn to nYn, nZ; see <u>Figure 10</u>	[1]								
		$V_{CC} = 2.0 V$		2.2	9.3	33	2.2	34	2.2	35	ns
		$V_{CC} = 3.0 V$		2.2	4.9	16.5	1.9	18	1.9	19.5	ns
		$V_{CC} = 3.3 V$		2.0	4.4	15.0	1.6	16.5	1.6	18.5	ns
		$V_{CC} = 4.5 V$		1.6	3.2	11.6	1.1	12.5	1.1	13.5	ns
		$V_{CC} = 6.0 V$		1.5	2.5	10.2	0.9	11	0.9	12	ns
		Sn to nZ, nYn; see <u>Figure 11</u>	[1]								
		$V_{CC} = 2.0 V$		7.7	16.8	38	6.3	40	6.3	42	ns
		$V_{CC} = 3.0 V$		4.9	8.8	20	3.9	21.5	3.9	23	ns
		$V_{CC} = 3.3 V$		4.4	7.9	17.5	3.4	19	3.4	22	ns
		$V_{CC} = 4.5 V$		3.2	5.8	14	2.3	15	2.3	17	ns
		$V_{CC} = 6.0 V$		2.4	4.8	12.6	1.6	14.5	1.6	16.5	ns
en	enable time	E to nZ, nYn; see <u>Figure 12</u>	[2]								
		$V_{CC} = 2.0 V$		10.5	20.5	47.5	8.5	52.5	8.5	57.5	ns
		$V_{CC} = 3.0 V$		6.2	10.6	45	5.2	50	5.2	55	ns
		$V_{CC} = 3.3 V$		5.6	9.4	42.5	4.6	47.5	4.6	52.5	ns
		$V_{CC} = 4.5 V$		4.2	6.9	40	3	45	3	50	ns
		$V_{CC} = 6.0 V$		3.2	5.6	39	2.2	40	2.2	40	ns
dis	disable time	E to nZ, nYn; see <mark>Figure 12</mark>	[3]								
		$V_{CC} = 2.0 V$		39.5	75.4	100	39.3	105	39	115	ns
		$V_{CC} = 3.0 V$		35.2	69.5	90	35.5	100	35	110	ns
		$V_{CC} = 3.3 V$		34.6	68.1	85	34.6	95	34.5	105	ns
		$V_{CC} = 4.5 V$		28.5	63	80	28.2	90	28	100	ns
		$V_{CC} = 6.0 V$		14.4	57.9	78	13.5	80	13.0	80	ns
CPD	power dissipation capacitance	per channel; see <u>Figure 13</u>	<u>[4]</u>								
		$V_{CC} = 3.3 V$		-	42	-	-	-	-	-	pF
		$V_{CC} = 5.0 V$		-	47	-	-	-	-	-	pF

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Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control

25 °C -40 °C to +85 °C -40 °C to +125 °C Unit Symbol Parameter Conditions Min Max Min Max Min Тур Max 74HCT4852-Q100 [1] propagation delay nZ, nYn to nYn, nZ; t_{pd} see Figure 10 $V_{CC} = 4.5 V$ 1.6 11.5 12.5 13.5 3.5 1.1 1.1 <u>[1]</u> Sn to nZ, nYn; see Figure 11 $V_{CC} = 4.5 V$ 3.2 7.6 13 2.3 15 1.6 17 E to nZ, nYn; [2] enable time t_{en} see Figure 12 $V_{CC} = 4.5 V$ 4.2 8.3 25 3.0 30 3.0 35 E to nZ, nYn; [3] disable time t_{dis} see Figure 12 $V_{CC} = 4.5 V$ 28.5 61.8 80 28.2 90 28.0 100 [4] power dissipation per channel; CPD capacitance see Figure 13 $V_{CC} = 5.0 V$ 47 ------

Dynamic characteristics ... continued Table 9.

At recommended operating conditions; voltages are referenced to GND (ground 0 V); for load circuit see Figure 14.

[1] t_{pd} is the same as t_{PLH} and t_{PHL}.

t_{en} is the same as t_{PZH} and t_{PZL}. [2]

[3] t_{dis} is the same as t_{PLZ} and t_{PHZ}.

 C_{PD} is used to determine the dynamic power dissipation (P_D in μW): [4]

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

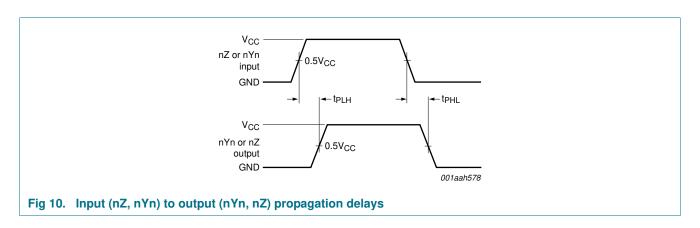
 Σ {(C_L + C_{sw}) × V_{CC}² × f_o} = sum of outputs;

 C_L = output load capacitance in pF;

C_{sw} = switch capacitance in pF;

V_{CC} = supply voltage in V.

12. Waveforms



ns

ns

ns

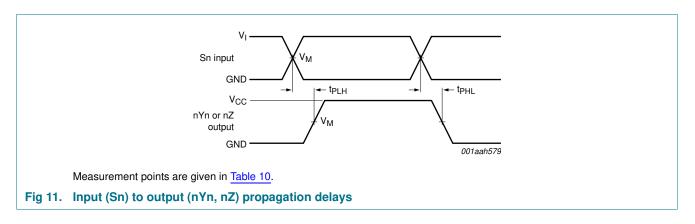
ns

pF

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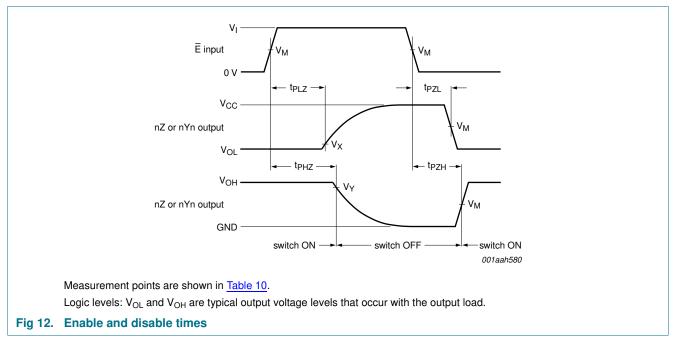
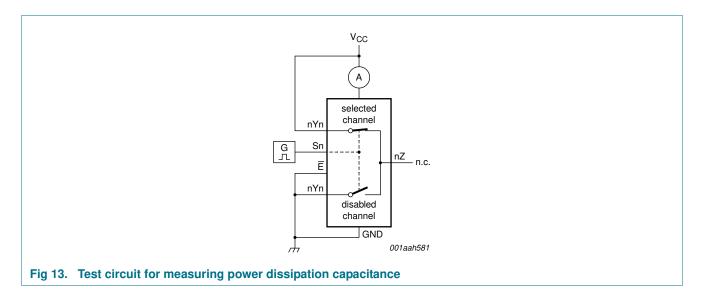


Table 10.Measurement points

Туре	Input		Output		
	V _M	VI	V _M	V _X	V _Y
74HC4852-Q100	0.5V _{CC}	V _{CC}	0.5V _{CC}	$V_{OL} + 0.1 (V_{CC} - V_{OL})$	0.9V _{OH}
74HCT4852-Q100	1.3 V	3.0 V	0.5V _{CC}	$V_{OL} + 0.1 (V_{CC} - V_{OL})$	0.9V _{OH}

Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control



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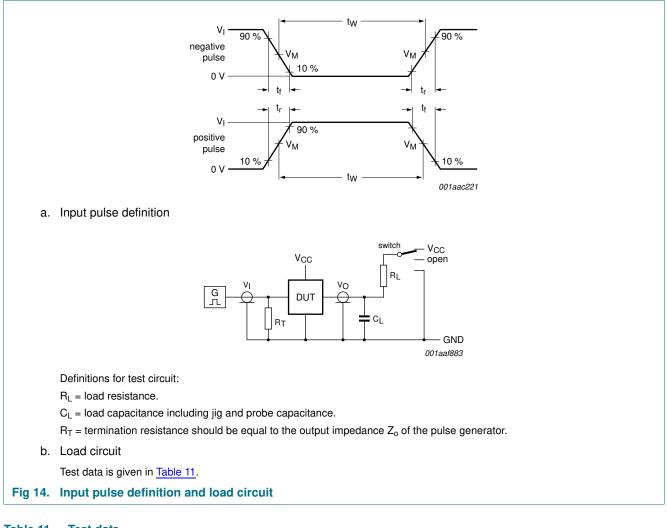


Table 11. Test data

Test	Input			Output		S1 position	
	Control E, Sn	Switch nYn (nZ)	t _r , t _f	Switch nZ (n)	'n)		
	V _I [1]	VI	_	CL	RL		
t _{PHL,} t _{PLH}	V _{CC}	V _{CC}	6 ns	50 pF	-	open	
t _{PHZ} , t _{PZH}	V _{CC}	V _{CC}	6 ns	50 pF	10 kΩ	GND	
t _{PLZ} , t _{PZL}	V _{CC}	V _{CC}	6 ns	50 pF	10 kΩ	V _{CC}	
C _{PD}	V _{CC}	V _{CC}	6 ns	0 pF	-	open	

[1] For 74HCT4852-Q100: input voltage $V_1 = 3.0 V$.

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13. Package outline

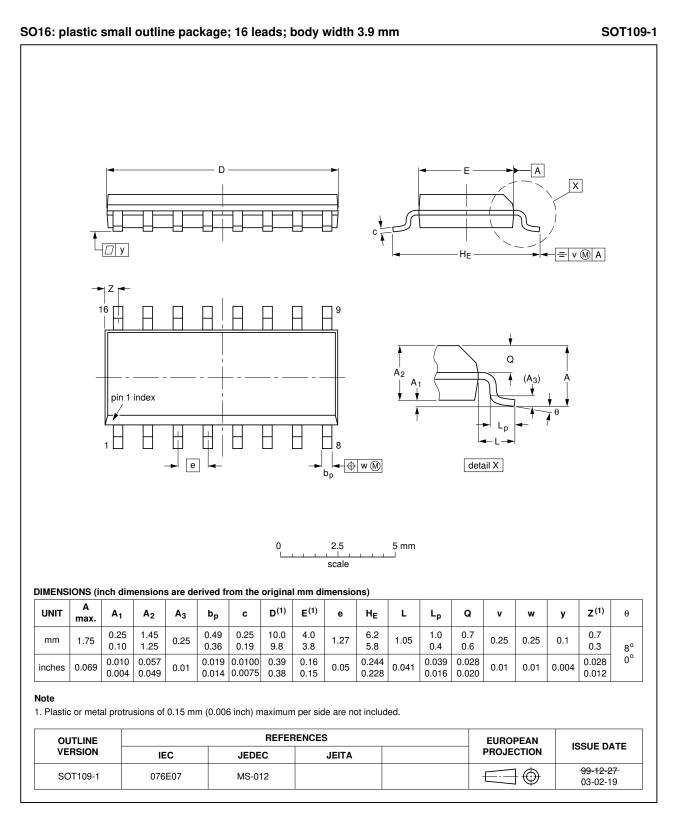


Fig 15. Package outline SOT109-1 (SO16)

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74HC HCT4852 Q100

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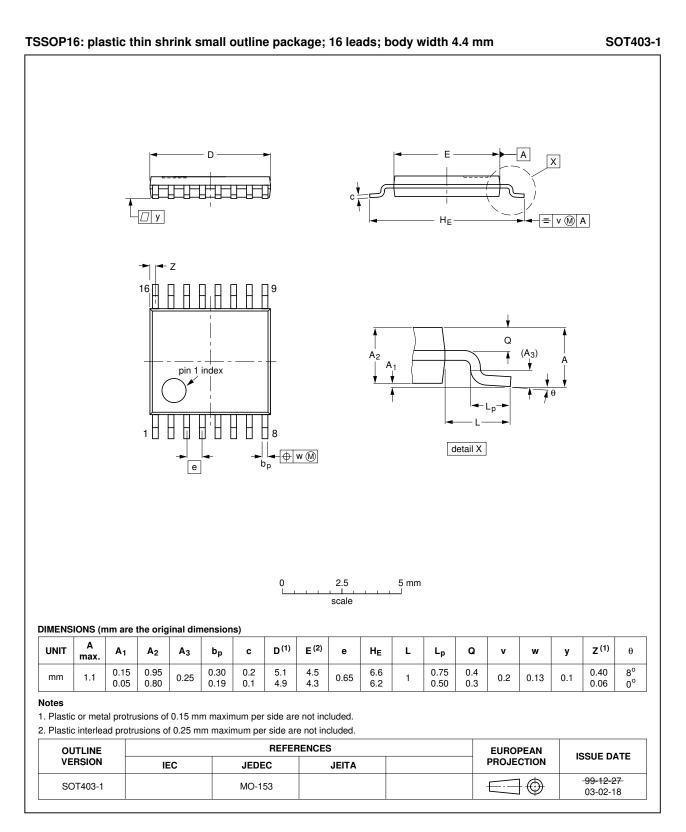
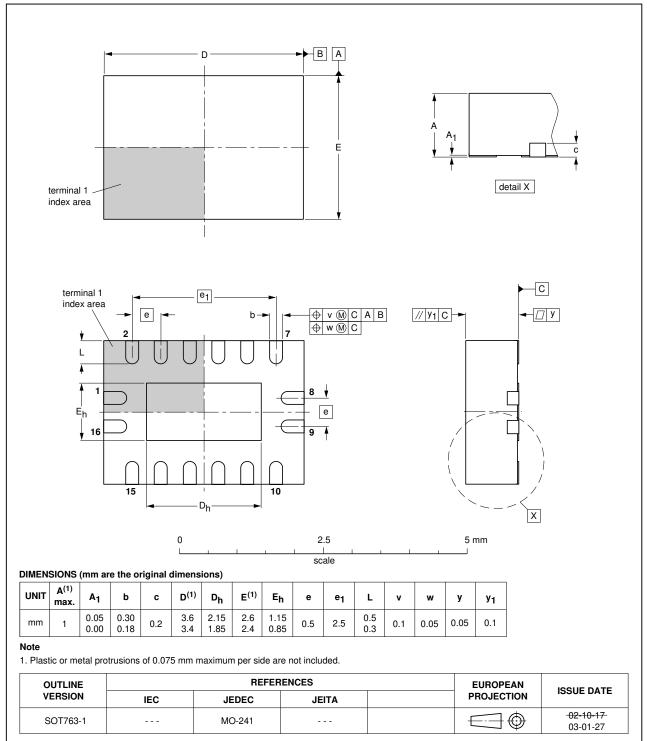


Fig 16. Package outline SOT403-1 (TSSOP16)

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DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

Fig 17. Package outline SOT763-1 (DHVQFN16)

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14. Abbreviations

Description Charged Device Model Complementary Metal Oxide Semiconductor
Complementary Metal Oxide Semiconductor
Device Under Test
ElectroStatic Discharge
Human Body Model
Machine Model

15. Revision history

Table 13. Revision histor	ſy			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4852_Q100_1	20120712	Product data sheet	-	-

Dual 4-channel analog multiplexer/demultiplexer with injection-current effect control

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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